

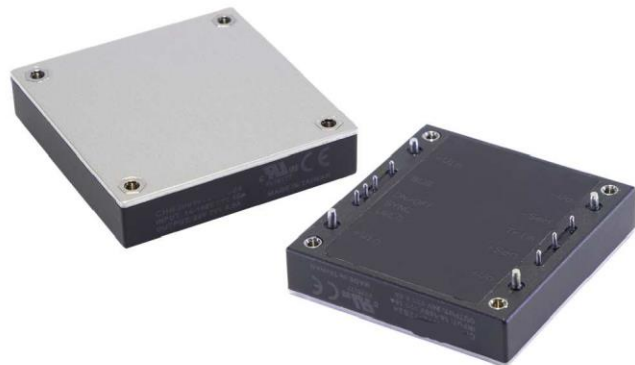


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200W Module DC to Dc power supply > CHB200W12

Features

- Efficiency Up to 90%
- Fixed Switching Frequency
- Regulated Outputs
- Remote On/Off
- Fully protected (OTP/OCP/OVP/UVLO)
- 3000Vac I/O Isolation
- Operating Case Temperature -40 to +100°C
- Half Brick Size Meet Industrial Standard
2.28x2.40x0.50
- CB Test Certificate IEC62368-1
- EN50155 Compliant with External Circuits
- UL62368-1 2nd (Reinforce Insulation) Approval
- Shock & Vibration EN50155 (EN61373) Compliant
- Fire & Smoke EN45545-2 Compliant
- 5000m Operating Altitude



MODEL NUMBER	INPUT VOLTAGE	OUTPUT VOLTAGE	OUTPUT CURRENT		INPUT CURRENT		% EFF.		CAPACITOR LOAD MAX.
			MIN.	MAX.	NO LOAD	FULL LOAD	(1)	(2)	
CHB200W12-72S12	14-160 VDC	12 VDC	0 mA	16.7 A	50 mA	3086 mA	90	90	16700uF
CHB200W12-72S15	14-160 VDC	15 VDC	0 mA	13.5 A	50 mA	3086 mA	90	89	13500uF
CHB200W12-72S24	14-160 VDC	24 VDC	0 mA	8.4 A	50 mA	3156 mA	88	88	8000µF
CHB200W12-72S48	14-160 VDC	48 VDC	0 mA	4.2 A	50 mA	3121 mA	89	89	2200µF

NOTE:

1. Nominal Input Voltage 72 VDC
2. Measured at 110Vin
3. An External Input Capacitor 100uF for All Models are Recommended to Reduce Input Ripple Voltage
4. An External Electrolytic Capacitor at least 240uF connected between BUS and -Vin is necessary

PART NUMBER

Series	Nominal Input Voltage	Number of Outputs	Nominal Output Voltage	Remote On/Off Logic	Mounting Inserts
CHB200W12-	II	O	XX	L	-Y (Option)
CHB200W12	72: 72 VDC	S: Single	12: 12VDC 15: 15VDC 24: 24VDC 48: 48VDC	None: Positive N: Negative	None: M3x0.5 Mounting Inserts -C: Clear Mounting Inserts (3.2mm DIA.)

Part Number Example:

CHB200W12-72S12N-C: Half Brick, 200W, 12:1 14-160Vdc Input, Single 12Vdc Output, Negative Logic, Clear Mounting Insert



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TECHNICAL SPECIFICATIONS

(All specifications are typical at nominal input, full load at 25°C unless otherwise noted.)

ABSOLUTE MAXIMUM RATINGS

PARAMETER	NOTES and CONDITIONS	Device	Min.	Typ.	Max.	Units
Input Voltage	Continuous	All	-0.3		160	V _{dc}
Input Surge Voltage	100ms max.	All			180	V _{dc}
Operating Case Temperature	At the Center Part of Base Plate	All	-40		100	°C
Storage Temperature		All	-55		125	°C

INPUT CHARACTERISTICS

PARAMETER	NOTES and CONDITIONS	Device	Min.	Typ.	Max.	Units
Operating Input Voltage		All	14	72	160	V _{dc}
Input Under Voltage Lockout						
Turn-On Voltage Threshold		All	12.5	13	13.5	V _{dc}
Turn-Off Voltage Threshold		All	10.5	11	11.5	V _{dc}
Lockout Hysteresis Voltage		All		2		V _{dc}
Maximum Input Current	V _{in} =16.5V, Full Load.	All		15		A
No-Load Input Current	V _{in} =72V, I _o =0A	See Model Number Table				mA
Input Filter	Pi filter.	All				
Inrush Current (I ² t)	As per ETS300 132-2.	All			0.1	A ² s
Input Reflected Ripple Current	P-P thru 12uH inductor, 5Hz to 20MHz.	All		50		mA

OUTPUT CHARACTERISTICS

PARAMETER	NOTES and CONDITIONS	Device	Min.	Typ.	Max.	Units
Voltage Set Point Accuracy	V _{in} =72V, Full Load, T _c =25°C	All	-1.0		+1.0	%
Output Voltage Regulation						
Load Regulation	Full Load to No Load	All			±0.2	%
Line Regulation	V _{in} =High Line to Low Line, Full Load	All			±0.2	%
Temperature Coefficient	T _c =-40°C to 100°C	All			±0.02	%/°C
Output Voltage Ripple and Noise (5Hz to 20MHz bandwidth)						
Peak-to-Peak	Full load, 10uF tantalum and 1.0uF ceramic capacitors (for V _o =48V: Full Load 10uF aluminum and 1uF ceramic capacitors).	12V _o			200	mV
		15V _o			200	
		24V _o			240	
		48V _o			240	
RMS.		12V _o			80	mV
		15V _o			60	
		24V _o			100	
		48V _o			100	
Output Current Range	V _{in} = 16.5 to 160V	See Model Number Table			A	
	V _{in} = 14 to 16.5V	See Model Number Table, Full Load 10S				
Over Current Protection	<90% V _o	All	110	125	140	%
Short Circuit Protection	Hiccup Mode. Auto Recovery.	All	Continuous, Auto Recovery.			
External Load Capacitance	Full load (Constant resistive load)	See Model Number Table			uF	
Output Voltage Trim Range	P _o ≤ max rated power, I _o ≤ I _{o_max}	All	-20		+15	%
Output Voltage Remote Sense Range	P _o ≤ max rated power, I _o ≤ I _{o_max} % of nominal V _o	All			+15	%
Over Voltage Protection	Limited Voltage, % of Nominal V _o	All	117	125	140	%



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EFFICIENCY

PARAMETER	NOTES and CONDITIONS	Device	Min.	Typ.	Max.	Units
100% Load	V _{in} =72V, 110V	See Model Number Table				%

DYNAMIC CHARACTERISTICS

PARAMETER	NOTES and CONDITIONS	Device	Min.	Typ.	Max.	Units
Output Voltage Current Transient						
Error Band	75% to 100% of I _{o_max} step load change d _i /d _t =0.1A/us	All			±5	%
Recovery Time	(within 1% V _{out} nominal)	All			250	us
Turn-On Delay and Rise Time						
Turn-On Delay Time, From On/Off Control	Full load (Constant resistive load)					
Turn-On Delay Time, From On/Off Control	V _{on/off} to 10%V _{o_set} , Remote On	All		100		ms
Turn-On Delay Time, From Input	V _{in_min} to 10%V _{o_set} , Power Up	All		100		ms
Output Voltage Rise Time	10%V _{o_set} to 90%V _{o_set}	All		100		ms

ISOLATION CHARACTERISTICS

PARAMETER	NOTES and CONDITIONS	Device	Min.	Typ.	Max.	Units
Isolation Voltage (100% factory Hi-Pot tested @2sec.)	1 minute; Input to Output,	All			3000 4200	V _{ac} V _{dc}
	1 minute; Input to Case (Base Plate),	All			3000 4200	V _{ac} V _{dc}
	1 minute; Output to Case (Base Plate)	All			500 700	V _{ac} V _{dc}
Isolation Resistance	Input to Output	All	100			MΩ
Isolation Capacitance	Input to Output	All		500		pF
	Input to Case (Base Plate)	All		None		
	Output to Case (Base Plate)	All		2000		

FEATURE CHARACTERISTICS

PARAMETER	NOTES and CONDITIONS	Device	Min.	Typ.	Max.	Units
Switching Frequency	Output Ripple Frequency	All	432	480	528	KHz
On/Off Control, Positive Remote On/Off logic, Refer to -Vin pin.						
Logic Low (Module Off)	V _{on/off} at I _{on/off} =1.0mA	All	0		1.2	V
Logic High (Module On)	V _{on/off} at I _{on/off} =0.0uA, Pin open=On	All	3.5		160	V
On/Off Control, Negative Remote On/Off logic, Refer to -Vin pin						
Logic High (Module Off)	V _{on/off} at I _{on/off} =0.0uA, Pin open=Off	All	3.5		160	V
Logic Low (Module On)	V _{on/off} at I _{on/off} =1.0mA	All	0		1.2	V
On/Off Current (for both remote on/off logic)	I _{on/off} at V _{on/off} =0V	All		0.3	1	mA
Leakage Current (for both remote on/off logic)	Logic High, V _{on/off} =15V	All			30	uA
Off Converter Input Current	Shutdown input idle current	All		15	20	mA
Over Temperature Shutdown	Temperature at the Center Part of Base Plate, Non-Latching	All		105		°C
Over Temperature Recovery		All		95		°C

GENERAL SPECIFICATIONS

PARAMETER	NOTES and CONDITIONS	Device	Min.	Typ.	Max.	Units
MTBF	I _o =100% of I _{o_max} ; MIL-HDBK - 217F_Notice 1, GB, 25°C	72S12		475		K hours
		72S15		551		
		72S24		629		
		72S48		572		
Weight		All		105		grams
Case Material	Plastic, DAP, UL 94V-0					
Base plate Material	Aluminum					



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Potting Material	UL 94V-0		
Pin Material	Base: Copper Plating: Nickel with Matte Tin		
Shock/Vibration	MIL-STD-810F/EN61373 Compliant		
Humidity	95% RH max. Non Condensing		
Altitude	5000m Operating Altitude, 12000m Transport Altitude		
Thermal Shock	MIL-STD-810F		
Fire & Smoke	EN45545-2 Compliant		
EMI	Meets EN55032 & EN50155 Compliant (with external filter)		Class A
ESD	EN61000-4-2	Level 3: Air ± 8 kV, Contact ± 6 kV	Perf. Criteria A
Radiated immunity	EN61000-4-3	Level 3: 80~1000MHz, 20V/m	Perf. Criteria A
Fast Transient	EN61000-4-4	Level 3: On power input port, ± 2 kV, external input capacitor required,	Perf. Criteria A
Surge	EN61000-4-5	Level 4: Line to earth, ± 4 kV, Line to line, ± 2 kV	Perf. Criteria A
Conducted immunity	EN61000-4-6	Level 3: 0.15~80MHz, 10V	Perf. Criteria A
Interruptions of Voltage Supply	EN50155	Class S3: 20ms interruptions	Perf. Criteria A
Supply Change Over	EN50155	Class C2: During a supply break of 30 ms,	Perf. Criteria A

Immunity to Environmental Conditions.

Phenomenon	EN50155; 2017 Reference Clause(s)	Reference Standard	Test Conditions	Result
Low Temperature Start-up test	13.4.4	EN 60068-2-1	Class OT6 Temperature: -40°C Duration: 2 hrs	Pass
Dry Heat Test	13.4.5	EN 60068-2-2	Class OT6 & Cycle A (ST0) Temperature: 85°C Duration: 6 hrs Extended temperature: 100°C Extended Duration: 10min	Pass
Low Temperature Storage Test	13.4.6	EN 60068-2-1	Temperature: -40°C Duration: 16 hrs	Pass
Cyclic Damp Heat Test	13.4.7	EN 60068-2-30	Temperature: 25°C - 55°C Humidity: 90% RH Duration: 48 hrs	Pass
Random Vibration Test	13.4.11	EN 61373	Temperature: 20°C +/- 3°C Humidity: 66% +/-5% RH Frequency range: 5 ~ 150 Hz Vertical: 1.01 m/s^2 Transverse: 1.01 m/s^2 Longitudinal: 1.01 m/s^2 Duration: 10 min / axis	Pass
Simulated Long Life Test at Increased Random Vibration Levels	13.4.11	EN 61373	Temperature: 20°C +/-3°C Humidity: 66% +/-5% RH Frequency range: 5 ~ 150 Hz Vertical: 5.72 m/s^2 Transverse: 5.72 m/s^2 Longitudinal: 5.72 m/s^2 Duration: 5 hrs / axis	Pass
Shock Test	13.4.11	EN 61373	Temperature: 20°C +/-3°C Humidity: 66% +/-5% RH Frequency range: 5 ~ 150 Hz +/-Vertical: 50 m/s^2 +/-Transverse: 50 m/s^2 +/-Longitudinal: 50 m/s^2 Duration: 30ms x18 (Each axis 3 shocks)	Pass

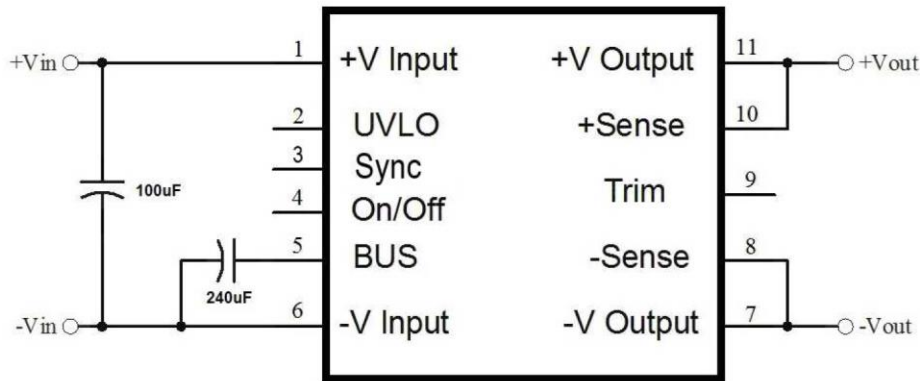


200W Module DC to Dc power supply > CHB200W12

EN45545-2 Fire & Smoke Test Conditions.

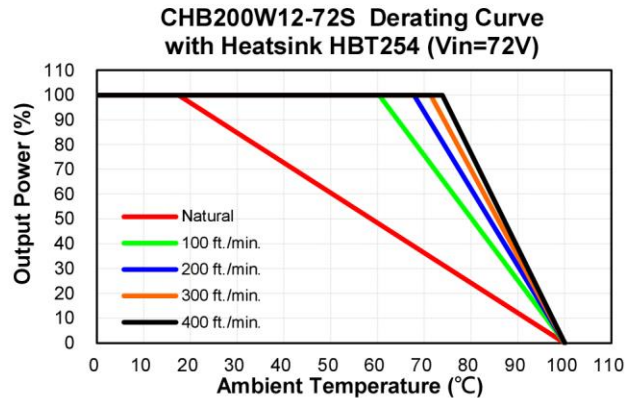
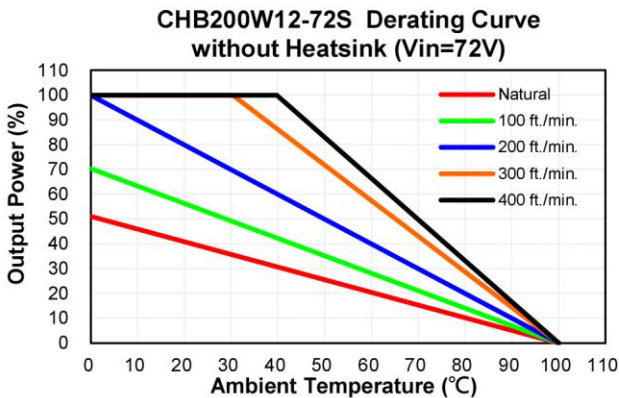
Item		Standard	Hazard Level
R22	Oxygen Index Test	EN 45545-2: 2013 EN ISO 4589-2: 2006	HL1, HL2, HL3
	Smoke Density Test	EN 45545-2: 2013 EN ISO 5659-2: 2013	HL1, HL2
	Smoke Toxicity Test	EN 45545-2: 2013 NF X70-100: 2006	HL1, HL2, HL3
R23	Oxygen Index Test	EN 45545-2: 2013 EN ISO 4589-2: 2006	HL1, HL2, HL3
	Smoke Density Test	EN 45545-2: 2013 EN ISO 5659-2: 2013	HL1, HL2, HL3
	Smoke Toxicity Test	EN 45545-2: 2013 NF X70-100: 2006	HL1, HL2, HL3
R24	Oxygen Index Test	EN45545-2: 2013 EN ISO 4589-2	HL1, HL2, HL3
R25	Glow - Wire Test	EN 45545-2:2013 EN 60695-2-11:2001	HL1, HL2, HL3
R26	Vertical Flame Test	EN 45545-2: 2013 EN 60695-11-10: 2013	HL1, HL2, HL3

CHARACTERISTIC CURVE



Simplified Application Circuit

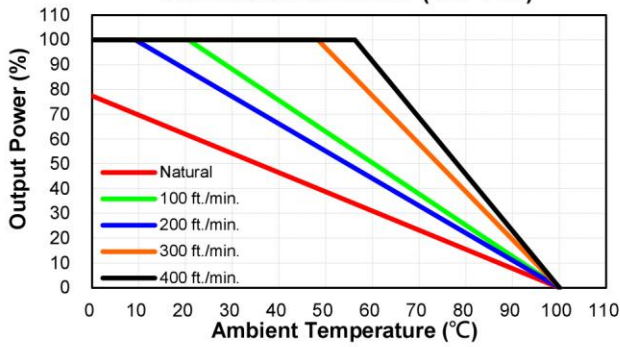
Power Derating Curve



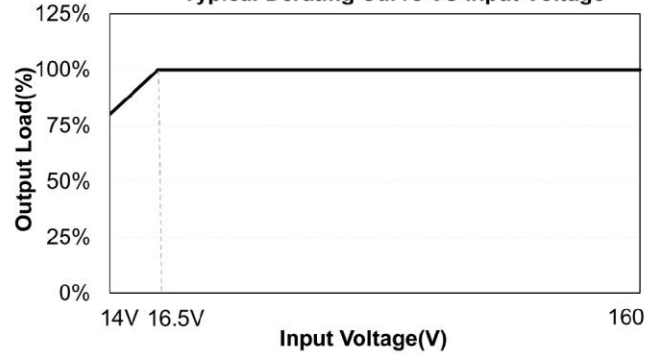


200W Module DC to DC power supply > CHB200W12

CHB200W12-72S Derating Curve with Heatsink HBT127 (Vin=72V)

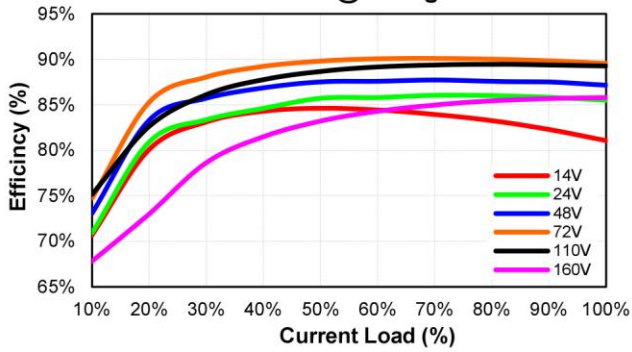


Typical Derating Curve VS Input Voltage

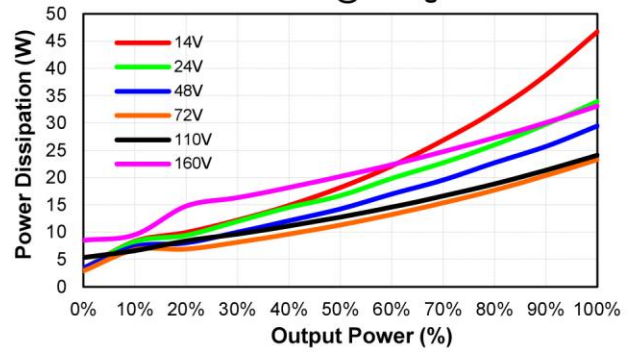


Performance Data

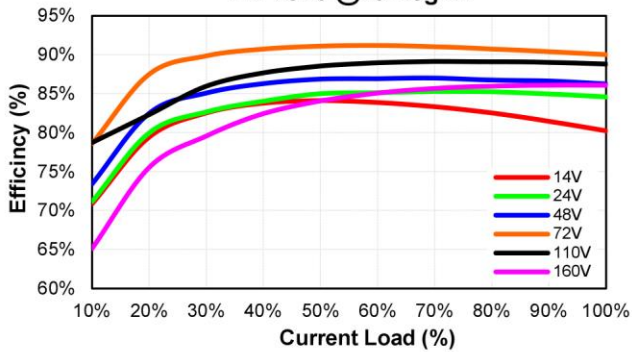
CHB200W12-72S12 Eff Vs Io @25 Deg. C



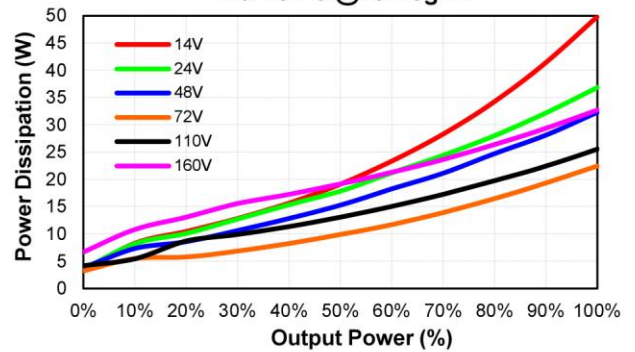
CHB200W12-72S12 Pd Vs Po @25 Deg. C



CHB200W12-72S15 Eff Vs Io @25 Deg. C

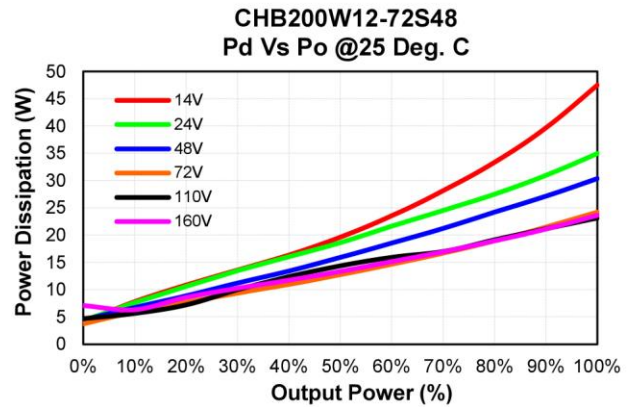
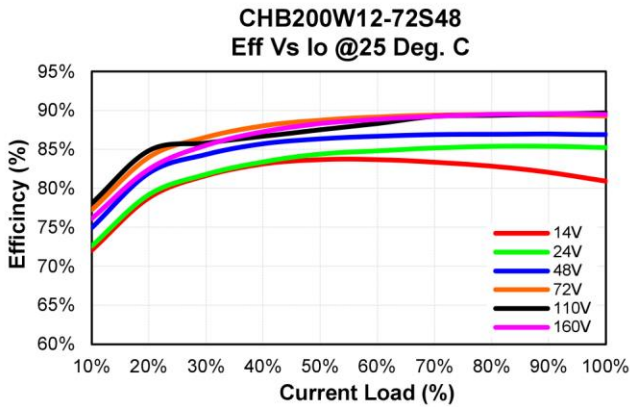
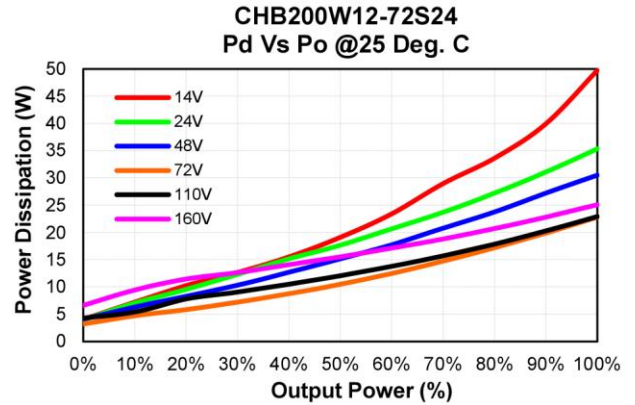
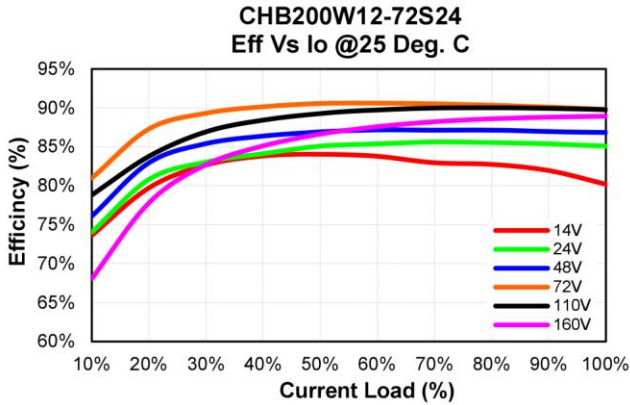


CHB200W12-72S15 Pd Vs Po @25 Deg. C





200W Module DC to DC power supply > CHB200W12



MECHANICAL SPECIFICATION

